BLF7G20L-90P; BLF7G20LS-90P Power LDMOS transistor

AMPLEON

Rev. 3 — 1 September 2015

Product data sheet

Product profile

1.1 General description

90 W LDMOS power transistor for base station applications at frequencies from 1800 MHz to 2000 MHz, designed for operation at 1427 MHz to 1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz.

Typical performance

Typical RF performance at $T_{case} = 25$ °C in a common source class-AB production test circuit.

Mode of operation	f	I_{Dq}	V _{DS}	P _{L(AV)}	Gp	η_{D}	ACPR _{400k}	ACPR _{600k}	EVM _{rms}
	(MHz)	(mA)	(V)	(W)	(dB)	(%)	(dBc)	(dBc)	(%)
CW	1805 to 1880	550	28	84	19	54	-	-	-
GSM EDGE	1805 to 1880	550	28	40	19.5	41	–61	-74	2.5

1.2 Features and benefits

- Excellent ruggedness
- High efficiency
- Low R_{th} providing excellent thermal stability
- Designed for broadband operation (1427 MHz to1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz)
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the frequency bands of 1427 MHz to 1525 MHz, 1805 MHz to 1880 MHz and 2110 MHz to 2170 MHz.

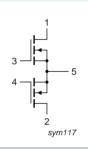
2. Pinning information

Table 2. Pinning

Description		Simplified outline	Graphic symbol
90P (SOT1121A)			
drain1			,
drain2		1 2 [~] [~]	
gate1			3
gate2			5
source	<u>[1]</u>	3 4	2 sym117
	drain1 drain2 gate1 gate2	drain1 drain2 gate1 gate2	-90P (SOT1121A) drain1 drain2 gate1 gate2

BLF7G20LS-90P (SOT1121B)

1	drain1	
2	drain2	
3	gate1	
4	gate2	
5	source	[1]



3. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BLF7G20L-90P	-	flanged LDMOST ceramic package; 2 mounting holes; 4 leads	SOT1121A		
BLF7G20LS-90P	-	earless flanged LDMOST ceramic package; 4 leads	SOT1121B		

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
V_{GS}	gate-source voltage		-0.5	+13	V
I_D	drain current		-	18	Α
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		-	200	°C

^[1] Connected to flange.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 80 °C; P_{L} = 90 W	0.49	K/W

6. Characteristics

Table 6. Characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_{D} = 0.5 \text{ mA}$	65	-	-	V
V _{GS(th)}	gate-source threshold voltage	V_{DS} = 10 V; I_{D} = 50 mA	1.5	1.9	2.3	V
I _{DSS}	drain leakage current	$V_{GS} = 0 \text{ V}; V_{DS} = 28 \text{ V}$	-	-	2	μА
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	8.2	9.5	-	Α
I_{GSS}	gate leakage current	V_{GS} = 11 V; V_{DS} = 0 V	-	-	200	nA
9 _{fs}	forward transconductance	V_{DS} = 10 V; I_{D} = 2.5 A	-	3.8	-	S
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 1.75 \text{ A}$	-	0.28	-	Ω

7. Test information

Table 7. Application information

f = 1805 MHz to 1880 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 550 mA; T_{case} = 25 °C; 2 sections combined unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Mode of o	peration: GSM EDGE; P _{L(AV)} = 40 W					
Gp	power gain		18.3	19.5	-	dB
RLin	input return loss		-	-15	-8	dB
η_{D}	drain efficiency		38	41	-	%
ACPR _{400k}	adjacent channel power ratio (400 kHz)		-	-61	-58	dBc
ACPR _{600k}	adjacent channel power ratio (600 kHz)		-	-74	-70.5	dBc
EVM_{rms}	RMS EDGE signal distortion error		-	2.5	3.8	%
EVM_M	peak EDGE signal distortion error		-	8	12.5	%
Mode of o	peration: CW; P _{L(AV)} = 84 W					
Gp	power gain		17.8	19	-	dB
η_{D}	drain efficiency		51	54	-	%

7.1 Ruggedness in class-AB operation

The BLF7G20L-90P and BLF7G20LS-90P are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions:

```
V_{DS} = 28 \text{ V; } I_{Dq} = 550 \text{ mA; } P_L = 90 \text{ W (CW), } f = 1805 \text{ MHz,} \\ V_{DS} = 28 \text{ V; } I_{Dq} = 380 \text{ mA; } P_L = 40 \text{ W (CW, half device), } f = 2110 \text{ MHz,} \\ V_{DS} = 28 \text{ V; } I_{Dq} = 380 \text{ mA; } P_L = 55 \text{ W (CW pulse, } 10 \text{ %, } 100 \text{ } \mu\text{s, halve device),} \\ f = 1427 \text{ MHz.}
```

7.2 One-tone CW

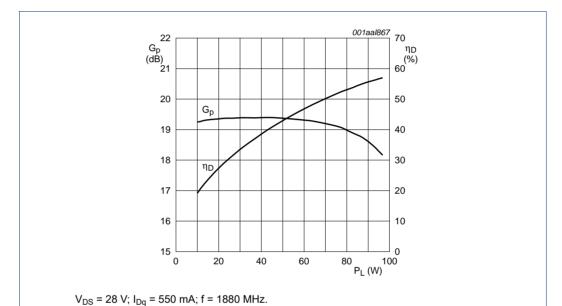


Fig 1. One-tone CW power gain and drain efficiency as function of load power; typical values

7.3 Two-tone CW

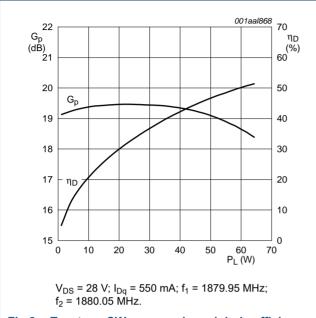


Fig 2. Two-tone CW power gain and drain efficiency as function of load power; typical values

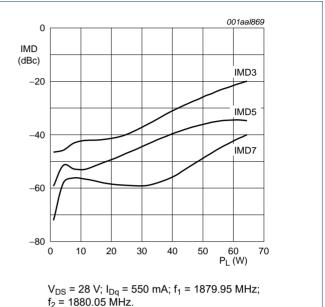


Fig 3. Two-tone CW intermodulation distortion as a function of load power; typical values

7.4 GSM EDGE

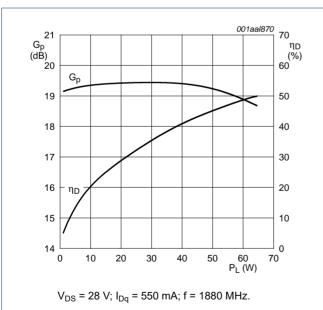


Fig 4. GSM EDGE power gain and drain efficiency as function of load power; typical values

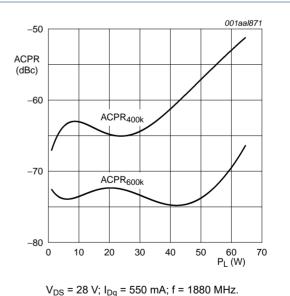
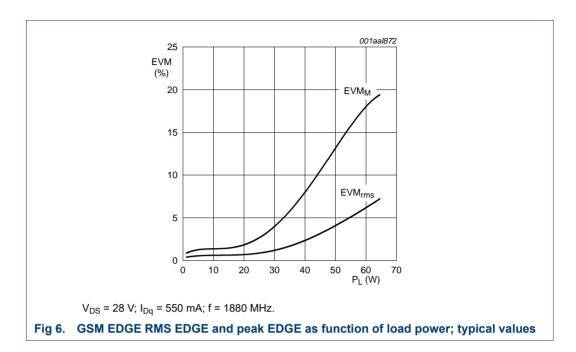


Fig 5. GSM EDGE ACPR at 400 kHz and at 600 kHz as function of load power; typical values



7.5 Single carrier IS-95

Single carrier IS-95 with pilot, paging, sync and 6 traffic channels (Walsh codes 8 - 13). PAR = 9.7 dB at 0.01 % probability on the CCDF. Channel bandwidth is 1.2288 MHz.

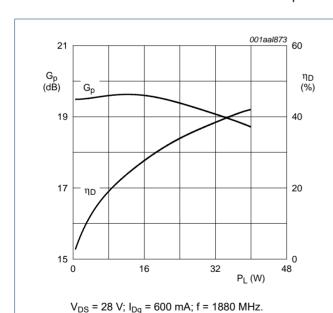
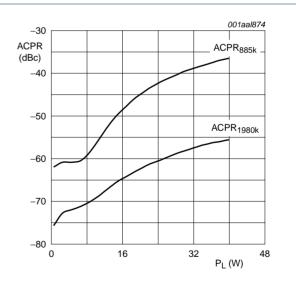
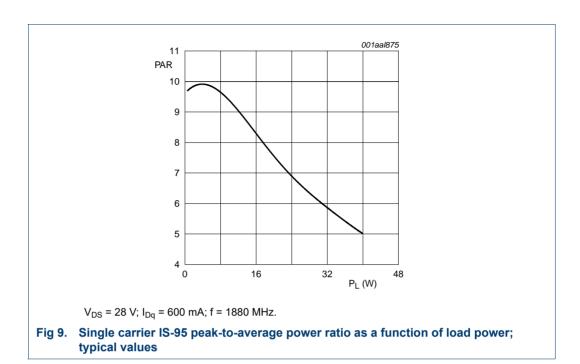


Fig 7. Single carrier IS-95 power gain and drain efficiency as function of load power; typical values



 V_{DS} = 28 V; I_{Dq} = 600 mA; f = 1880 MHz.

Fig 8. Single carrier IS-95 ACPR at 885 kHz and at 1980 kHz as function of load power; typical values



7.6 Single carrier W-CDMA

3GPP; test model 1; 64 DPCH; PAR = 7.2 dB at 0.01 % probability on CCDF. Channel bandwidth is 3.84 MHz.

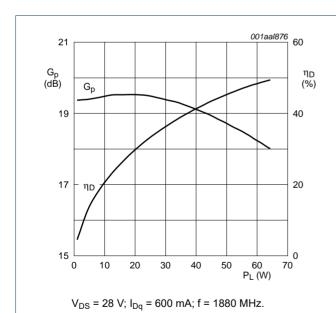
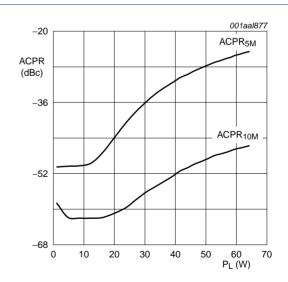


Fig 10. Single carrier W-CDMA power gain and drain efficiency as function of load power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 600 \text{ mA}; f = 1880 \text{ MHz}.$

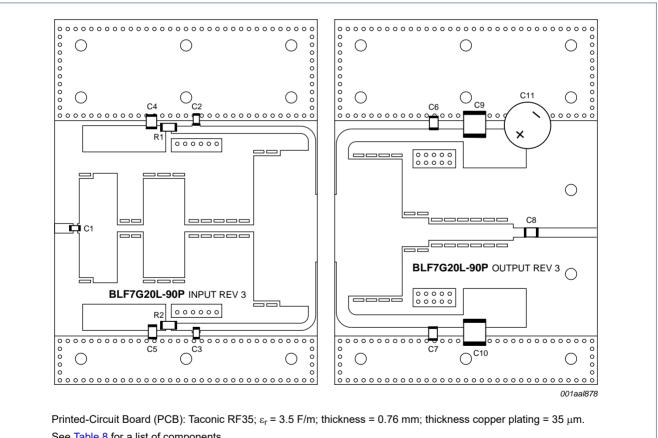
Fig 11. Single carrier W-CDMA ACPR at 5 MHz and at 10 MHz as function of load power; typical values

7.7 Test circuit

Table 8. List of components For test circuit see Figure 12.

Component	Description	Value	Remarks
C1, C2, C3	multilayer ceramic chip capacitor	24 pF	[1]
C4, C5	multilayer ceramic chip capacitor	4.7 μF	[2]
C6, C7, C8	multilayer ceramic chip capacitor	11 pF	[3]
C9, C10	multilayer ceramic chip capacitor	10 μF	[2]
C11	electrolytic capacitor	470 μF; 63 V	
R1, R2	SMD resistor	12 Ω	Philips 1206

- [1] American Technical Ceramics type 100A or capacitor of same quality.
- [2] TDK or capacitor of same quality.
- [3] American Technical Ceramics type 100B or capacitor of same quality.



See <u>Table 8</u> for a list of components.

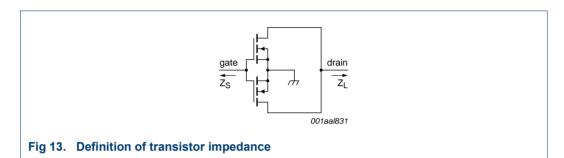
Fig 12. Component layout for class-AB production test circuit

7.8 Impedance information

Table 9. Typical impedance

Typical values valid for both section in parallel unless otherwise specified.

f	Z _S	Z _L
MHz	Ω	Ω
1800	1.0 – j3.3	2.8 – j2.7
1840	1.2 – j3.3	2.8 – j2.5
1880	1.1 – j3.4	2.7 – j2.4



8. Package outline

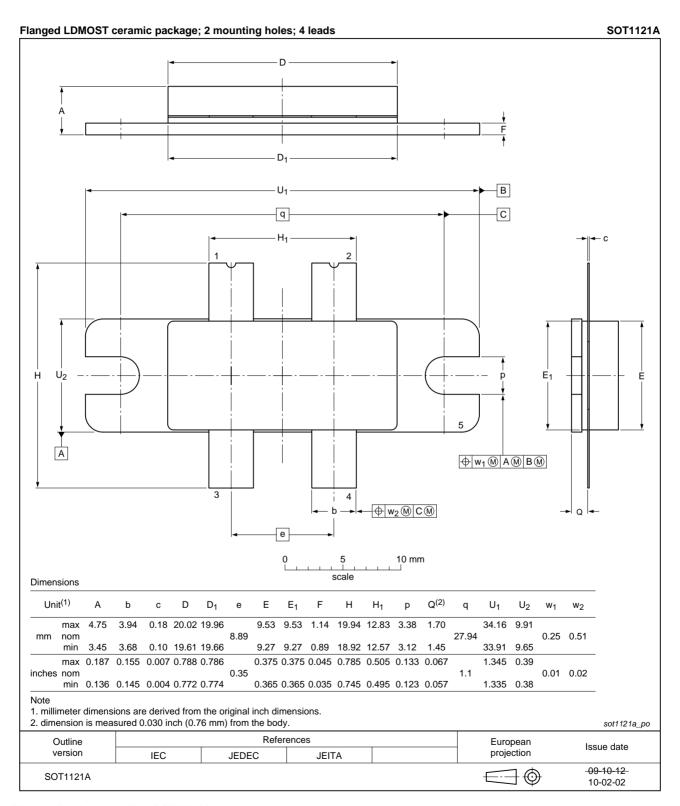


Fig 14. Package outline SOT1121A

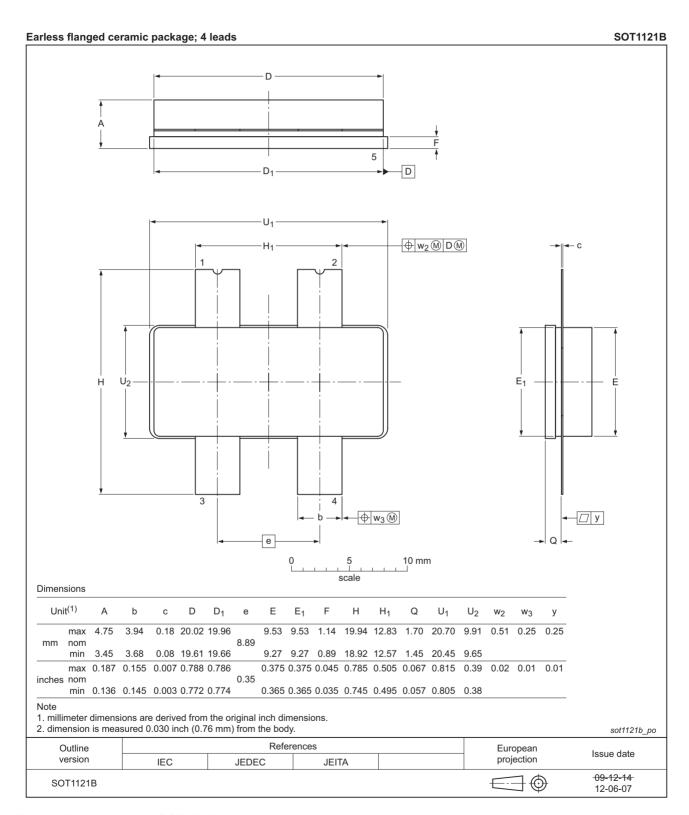


Fig 15. Package outline SOT1121B

9. Abbreviations

Table 10. Abbreviations

Table 10. Abbi	CVIALIONS
Acronym	Description
3GPP	3rd Generation Partnership Project
CW	Continuous Wave
CCDF	Complementary Cumulative Distribution Function
DPCH	Dedicated Physical Channel
EDGE	Enhanced Data rates for GSM Evolution
ESD	ElectroStatic Discharge
GSM	Global System for Mobile Communications
IS-95	Interim Standard 95
LDMOS	Laterally Diffused Metal Oxide Semiconductor
LDMOST	Laterally Diffused Metal Oxide Semiconductor Transistor
PAR	Peak-to-Average power Ratio
RF	Radio Frequency
SMD	Surface Mounted Device
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

10. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLF7G20L-90P_7G20LS-90P#3	20150901	Product data sheet	-	BLF7G20L-90P_7G20LS- 90P v.2	
Modifications:	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 				
BLF7G20L-90P_7G20LS-90P v.2	20111020	Product data sheet	-	BLF7G20L-90P_7G20LS- 90P v.1	
BLF7G20L-90P_7G20LS-90P v.1	20100428	Product data sheet	-	-	

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL https://www.ampleon.com.

11.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Ampleon does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Ampleon sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Ampleon and its customer, unless Ampleon and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Ampleon product is deemed to offer functions and qualities beyond those described in the Product data sheet.

11.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Ampleon does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Ampleon takes no responsibility for the content in this document if provided by an information source outside of Ampleon.

In no event shall Ampleon be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Ampleon' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Ampleon.

Right to make changes — Ampleon reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Ampleon products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an

Ampleon product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Ampleon and its suppliers accept no liability for inclusion and/or use of Ampleon products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Ampleon makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Ampleon products, and Ampleon accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Ampleon product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Ampleon does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Ampleon products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Ampleon does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Ampleon products are sold subject to the general terms and conditions of commercial sale, as published at http://www.ampleon.com/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Ampleon hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Ampleon products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

BLF7G20L-90P 7G20LS-90P#3

BLF7G20L-90P; BLF7G20LS-90P

Power LDMOS transistor

Non-automotive qualified products — Unless this data sheet expressly states that this specific Ampleon product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Ampleon accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Ampleon' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Ampleon' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Ampleon for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Ampleon' standard warranty and Ampleon' product specifications.

11.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own Any reference or use of any 'NXP' trademark in this document or in or on the surface of Ampleon products does not result in any claim, liability or entitlement vis-à-vis the owner of this trademark. Ampleon is no longer part of the NXP group of companies and any reference to or use of the 'NXP' trademarks will be replaced by reference to or use of Ampleon's own trademarks

12. Contact information

For more information, please visit: http://www.ampleon.com

For sales office addresses, please visit: http://www.ampleon.com/sales

BLF7G20L-90P; BLF7G20LS-90P

AMPLEON

Power LDMOS transistor

13. Contents

1	Product profile	. 1
1.1	General description	. 1
1.2	Features and benefits	. 1
1.3	Applications	. 1
2	Pinning information	. 2
3	Ordering information	. 2
4	Limiting values	. 2
5	Thermal characteristics	. 3
6	Characteristics	. 3
7	Test information	. 3
7.1	Ruggedness in class-AB operation	. 4
7.2	One-tone CW	
7.3	Two-tone CW	
7.4	GSM EDGE	
7.5	Single carrier IS-95	
7.6	Single carrier W-CDMA	
7.7	Test circuit	
7.8	Impedance information	. 9
8	Package outline	10
9	Abbreviations	12
10	Revision history	12
11	Legal information	13
11.1	Data sheet status	13
11.2	Definitions	13
11.3	Disclaimers	13
11.4	Trademarks	14
12	Contact information	14
42	Contonto	4 5

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for RF MOSFET Transistors category:

Click to view products by NXP manufacturer:

Other Similar products are found below:

MRF166W MHT1006NT1 FH2164 MRFE8VP8600HR5 BLF245 BLF278 ARF1511 ARF465BG BF 2030 E6814 BLF861A 3SK263-5TG-E VRF154FL MRF6S20010GNR1 DU1215S DU28200M VRF150MP MMRF1015NR1 MRF154 MRF175LU MRF6S20010GNR1
UF28100M MW6S010GNR1 MW6S010GNR1 DU2820S SD2943W SD2932BW SD2941-10W MRF24301HR5 ARF469AG
ARF463BP1G MMRF1019NR4 MHT1008NT1 MMRF1014NT1 MRF426 MRF422 BLW96 ARF468AG VRF161MP ARF468BG
MRFE6VP61K25NR6 MRFE6VP5300NR1 A2T27S020NR1 MMRF1304NR1 MRFE6S9060GNR1 MMRF1008GHR5 A2T27S007NT1
AFT09MP055NR1 DU2860U MHT1803A D2081UK.F